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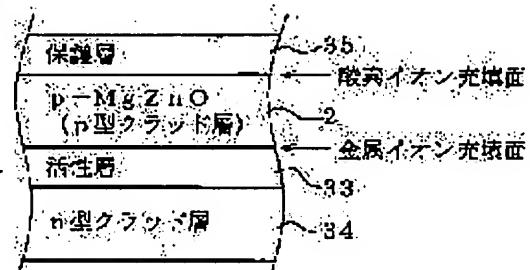
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## (54) LIGHT EMITTING ELEMENT AND ITS FABRICATING METHOD, VISIBLE LIGHT EMITTING DEVICE

### (57)Abstract:

**PROBLEM TO BE SOLVED:** To provide a light emitting element in which an emission layer part can be grown at a relatively low temperature using a small quantity of rare metal and high luminance emission can be ensured in blue light region and UV region.

**SOLUTION:** The light emitting element 1 has an emission layer part where a p-type clad layer 2, an active layer 33 and an n-type clad layer 34 are formed sequentially in this order and the p-type clad layer 2 comprises a p-type  $Mg_xZn_{1-x}O$  layer ( $0 < x \leq 1$ ). When that layer is formed by MOVPE method, missing of oxygen can be suppressed effectively during film deposition and a p-type  $Mg_xZn_{1-x}O$  layer having good characteristics can be obtained.



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